

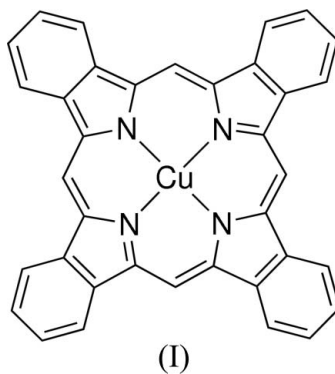
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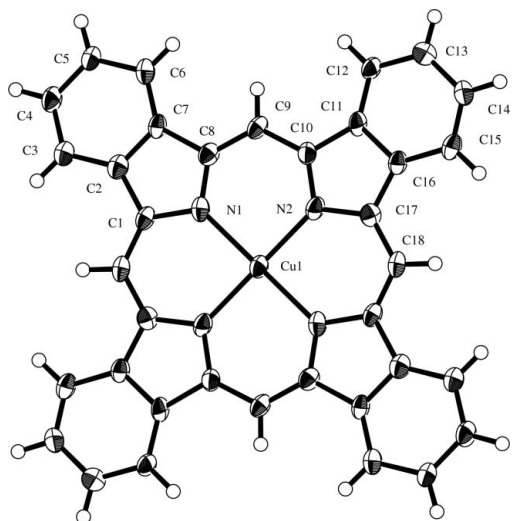
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Key indicators

Single-crystal X-ray study
 $T = 93$ K
Mean $\sigma(C-C) = 0.008$ Å
 R factor = 0.099
 wR factor = 0.266
Data-to-parameter ratio = 11.5For details of how these key indicators were automatically derived from the article, see <http://journals.iucr.org/e>.**[29*H*,31*H*-Tetrabenzo[*b,g,l,q*]porphinato(2-)- $\kappa^4 N^{21}, N^{22}, N^{23}, N^{24}$]copper(II)**The molecule of the title compound, $[Cu(C_{36}H_{20}N_4)]$, is not entirely planar in the crystal structure (*i.e.* not D_{4h}), but is slightly deformed, with only C_i symmetry. The molecules are stacked along the b axis in a herring-bone fashion.Received 7 September 2006
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Comment

We have recently reported that 29*H*,31*H*-tetrabenzo- $[b,g,l,q]$ porphin (abbreviated to H_2P) exhibits an excellent field-effect transistor (FET) characteristic (Aramaki *et al.*, 2004) and that the structure of H_2P is similar to that of metal-free β -phthalocyanine (*i.e.* the phthalocyanine analogue of H_2P) (Aramaki & Mizuguchi, 2003). An appealing feature of our FET system is the use of a soluble precursor of H_2P and its thermal transformation into H_2P directly on the substrate at about 473 K. The title compound (CuP), (I), is found to show an even better FET performance, as characterized by a high mobility of about 1.3 cm²/Vs (Aramaki *et al.*, 2006), compared with about 0.017 cm²/Vs in H_2P (Aramaki *et al.*, 2004). In this connection, the present structure analysis has been carried out in order to study the correlation between the crystal structure and the FET characteristics.The molecular structure of (I) is shown in Fig. 1. The molecular symmetry is not D_{4h} but C_i , because the molecule, located on an inversion centre, is not entirely flat. The angles between the plane of the four N atoms [$N1/N1^1/N2/N2^1$; symmetry code: (i) $1 - x, 1 - y, 1 - z$] and the planes of the benzene rings C2–C7 and C11–C16 are 6.1 (2) and 5.4 (2)°, respectively; the angle between the benzene rings is 0.9 (2)°. The present situation is quite similar to that of H_2P , where the corresponding dihedral angles are 6.42 (1)– 6.96 (1)° and 0.5 (1)°, respectively (Aramaki & Mizuguchi, 2003).Fig. 2 shows the molecular arrangement of (I). The molecules are arranged in a herring-bone fashion along the b axis, which is typical of porphin (Aramaki & Mizuguchi, 2003) and

**Figure 1**

A view of the molecular structure of (I), showing 50% probability displacement ellipsoids. Unlabelled atoms are related to labelled atoms by the symmetry operation $(1 - x, 1 - y, 1 - z)$.

phthalocyanine compounds (Matsumoto *et al.*, 1999). As judged from the space group, lattice parameters and molecular arrangement, CuP is found to be isomorphous with H_2P (isomorphous replacement of 2H by Cu).

Experimental

[1,4,8,11,15,18,22,25-Octahydro-1,4:8,11:15,18:22,25-tetraethano-29H,31H-tetrabenzob[*b,g,l,q*]porphinato(2-)- $\kappa N^{29}, \kappa N^{30}, \kappa N^{31}, \kappa N^{32}$]-copper(II) is a precursor that gives the title compound (CuP), (I), by thermal decomposition. The precursor was prepared according to the method of Ito *et al.* (2000). Single crystals of (I) were grown directly by thermal decomposition of the precursor at about 610 K in a closed system under high vacuum. A number of tiny needle crystals were obtained over a period of 72 h.

Crystal data

[Cu(C₃₆H₂₀N₄)]
 $M_r = 572.11$
 Monoclinic, $P2_1/n$
 $a = 12.339$ (2) Å
 $b = 6.5940$ (12) Å
 $c = 14.908$ (3) Å
 $\beta = 101.537$ (12)°
 $V = 1188.5$ (4) Å³

$Z = 2$
 $D_x = 1.599$ Mg m⁻³
 Cu $K\alpha$ radiation
 $\mu = 1.58$ mm⁻¹
 $T = 93$ K
 Needle, black
 $0.10 \times 0.02 \times 0.02$ mm

Data collection

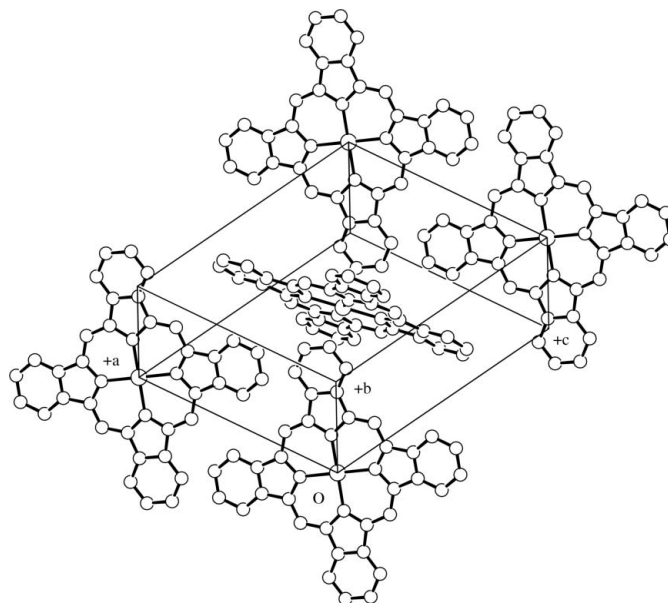
Rigaku R-AXIS RAPID-F imaging-plate diffractometer
 ω scans
 Absorption correction: multi-scan (ABSCOR; Higashi, 1995)
 $T_{\min} = 0.860$, $T_{\max} = 0.969$

11140 measured reflections
 2161 independent reflections
 1347 reflections with $F^2 > 2\sigma(F^2)$
 $R_{\text{int}} = 0.206$
 $\theta_{\text{max}} = 68.3^\circ$

Refinement

Refinement on F^2
 $R[F^2 > 2\sigma(F^2)] = 0.099$
 $wR(F^2) = 0.266$
 $S = 1.02$
 2161 reflections
 188 parameters

H-atom parameters constrained
 $w = 1/[\sigma^2(F_o^2) + (0.1369P)^2]$
 where $P = (F_o^2 + 2F_c^2)/3$
 $(\Delta/\sigma)_{\text{max}} < 0.001$
 $\Delta\rho_{\text{max}} = 1.43$ e Å⁻³
 $\Delta\rho_{\text{min}} = -0.55$ e Å⁻³

**Figure 2**

The packing arrangement in (I). H atoms have been omitted

Table 1

Selected geometric parameters (Å, °).

Cu1—N1	2.027 (5)	N1—C8	1.373 (8)
Cu1—N2	2.001 (4)	N2—C10	1.374 (8)
N1—C1	1.395 (8)	N2—C17	1.391 (8)
N1—Cu1—N2		90.0 (2)	

All H atoms were placed in geometrically idealized positions and constrained to ride on their parent atoms, with C—H = 0.95 Å and with $U_{\text{iso}}(\text{H}) = 1.2U_{\text{eq}}(\text{C})$. The highest residual density peak of 1.43 e Å⁻³ is located 1.2 Å from atoms N1 and Cu1.

Data collection: *PROCESS-AUTO* (Rigaku, 1998); cell refinement: *PROCESS-AUTO*; data reduction: *CrystalStructure* (Rigaku/MS, 2005); program(s) used to solve structure: *SIR2002* (Burla *et al.*, 2003); program(s) used to refine structure: *SHELXL97* (Sheldrick, 1997); molecular graphics: *ORTEPIII* (Burnett & Johnson, 1996); software used to prepare material for publication: *CrystalStructure*.

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